物質構造科学研究所放射光共同利用実験申請書 Application form for synchrotron radiation experiments at Photon Factory (PF)

物質構造科学研究所長 殿

ビームタイム合計

Total of beam time

	区分 Category		実験責任者 Spokesperson					申請日	Date	2013/11/11
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	実験課題名 Proposal title (英 訳) Mechanism of magnetostructural transformation in GaCMn3 type Antiperovskites EXAFS Study								pe Antiperovskites:	
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	う野キーワード rds for research field	I		structural phase transition		magnet	ism			
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	F法キーワード rds for experimental	methods		XAFS						
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	ステーション Station		year/month		希望時間 beam tim		氏 名(Name) <mark>Emura Shuichi</mark>		•	
BL-12	<u>2C</u>	20	2014-4 - 2014		120hours	\exists	所属·職名(Affilia <mark>Osaka Universi</mark>		n)	
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Tel.

120 hours(5 days)

受理年月日	2013/11/12		
受理番号	2014G042		

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The main aim of this proposal is to understand the mechanism of magneto-structural transformation in $AXMn_3$ (X = C and A = Ga, Sn, In, Ge) type antiperovskites by studying XAFS of constituent elements as a function of temperature. These materials undergo magnetic transformation from either *paramagnetic to ferrimagnetic* or *ferromagnetic to antiferromagnetic* phase depending on the A site atom. The magnetic transformation is also associated with *cubic-cubic volume discontinuous structural transition*. Being a cubic-cubic transformation, diffraction techniques have limited scope to explain the magneto-structural transformation especially since the magnetic order is antiferromagnetic or ferrimagnetic. Secondly, the magneto-structural transformation is believed to be dependent on Mn-C hybridization. Therefore, what is the role of A site atom in modulating the magnetic ordering? How does the hybridization between Mn and C atoms change during the magneto-structural transformation? To seek answers to these questions XAFS (XANES + EXAFS) investigations as a function of temperature in these antiperovskite materials are proposed.

We propose to study Mn K and Ga K EXAFS in the high volume and low volume phases of GaCMn₃. These studies will allow us to determine Mn-C nearest neighbor and Mn-Mn next nearest neighbor bond distances and map any kind of local structural disorder that takes place as a result of first order magnetic transition. Study of XANES at the Mn and Ga K edges will shed light on changes in hybridization taking place between the nearest neighbors.

A change in magnetic nature of first order magnetic transition can be achieved by substitution at the A site. For example the transformation which is from ferromagnetic to antiferromagnetic type in $GaCMn_3$ changes to paramagnetic to ferrimagnetic in $SnCMn_3$. A temperature dependent study of local structural study around the metal ions in compounds of the type $A_{1-x}A'_xCMn_3$ (A and A' = Ga, Sn, Ge, In) will enable to develop an understanding of the factors responsible for the above change in magnetic transformation.

Therefore it is also proposed to conduct temperature dependent EXAFS study across magnetic transitions in above class of materials. With these proposed experiments we intend to unravel all factors responsible for magneto-structural transformation in *AXMn*₃ type antiperovskites.

IV. Proposed experimental method and layout (schemes can be included). The reason why you choose the station or required beam specification (photon energy, flux, beam size, etc). Justify the requested amount of beam time.

It is planned to record Mn K edge XAFS in transmission at four different temperatures. XAFS data will be recorded from -200 eV to about 1000 eV with respect to the absorption edge.

The following compounds belonging to GaCMn₃ type antiperovskites prepared by solid state reaction will be taken up for EXAFS study:

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\begin{split} &Ga_{1\text{-y}}Sn_yCMn_3 \ (y=0,\ 0.2,\ 0.4,\ 0.5,\ 0.6,\ 0.8\ and\ 1). \\ &Ga_{1\text{-y}}Ge_yCMn_3 \ (y=0.1,\ 0.2,\ 0.3,\ 0.4\ and\ 0.5) \\ &Sn_{1\text{-y}}Zn_yCMn_3 \ (y=0.2,\ 0.4,\ 0.5,\ 0.6,\ 0.8\ and\ 1) \\ &Ga_{1\text{-y}}In_yCMn_3 \ (y=0.1,\ 0.2,\ 0.4,\ 0.6,\ 0.8,\ 0.9\ and\ 1) \end{split}
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Mn K edge energy is 6539 eV and Ga K edge at 10367 eV Other metal ions except Sn and In also have their K edge energies in the range 10 - 11 KeV which are perfectly suited for XAFS beamline 12C at Photon Factory. This beamline has the facility of recording XAFS at several temperatures below room temperature right down to 10K.

Total time proposed is calculated as follows:

- Total no. of scans at Mn K edge (25 samples) at each temperature 25
- Total no. of temperatures 4
- Time for one XAFS (XANES + EXAFS) scan in transmission mode 1 h each
- Total time for XAFS 100 hours
- Total time for EXAFS at K edges of other metal ions 12 hours
- Time for beamline alignment etc -2 hours
- Time taken for cryostat cooling and warming 6 hours

Total beamtime requested at the XAFS beamline 120 hours (15 shifts)

試料名<u>(必須)</u>、試料および実験法に関する安全性に対する記述、対策 (化学、生物、放射線、高電圧、高圧ガス、真空汚染等) List of samples (Obligatory). Remarks and safety measures against possible hazards (chemicals, biological materials, radiation, high voltage, high pressure, contamination of vacuum, etc.). GaCMn3, Ga0.8Sn0.2CMn3, Ga0.6Sn0.4CMn3, Ga0.5Sn0.5CMn3, Ga0.4Sn0.6CMn3, GaO.2SnO.8CMn3 and SnCMn3 - safe to handle, no hazards GaO.8GeO.2CMn3, GaO.7GeO.3CMn3, GaO.5GeO.5CMn3 - safe to handle, no hazards Sn0.8In0.2CMn3, Sn0.6In0.4CMn3, Sn0.4In0.6CMn3, Sn0.2In0.8CMn3 - safe to handle, no hazards Gao.8Ino.2CMn3, Gao.6Ino.4CMn3, Gao.4Ino.6CMn3, Gao.2Ino.8CMn3 and InCMn3 - safe to handle, no hazards ,本申請に係わる先行課題での成果·論文、本申請に関わる試料·装置の準備状況 Accomplishment and/or publications in your previous research programs in related fields. Status of sample/equipment preparation. The Spokesperson and Local contact are both well versed with EXAFS technique and PF beamlines. As a part of past proposals, PF beamlines 12C, 7C, 9C etc have been used to record XANES and EXAFS on several type of compounds. In addition the Spokesperson has used XAFS beamlines at different synchrotron centers like Elettra, SPring-8, Soliel, etc. Several publications have resulted from these experiments and the registration numbers of publications from PF beamline are given below. More papers are in review process or in process of submission . PF出版データベース登録番号 (Registration numbers of your papers in PF Publication DB) 20080442, 20100410, 20100638, 20110202, 20110513, 20130013 . 外部資金獲得状況 (Financial support concerning this research project) Financial support will be sought from Govt. of India and Goa University .必要とする装置・器具 (Equipment to be used) 施設にある装置、器具 (Facilities and equipment in PF) 持ち込む装置、器具 (Equipment you bring to PF) BL 12C or BL 9C in transmission mode and low None temperature cryostat P型課題の場合、以下の項目をチェックしてください。 For P category applications 1.ステーション担当者との打ち合わせは済みましたか? 2.実験タイプは? Have you consulted with responsible beamline staff? Which type of application? 済み (Yes, I have) 初心者型 予備実験型

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担当者(

Responsible beamline staff's name

Test experiments

Beginners